NSN 5961-01-273-6734

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-273-6734 **Inclosure Material:** Glass **Overall Length:** 0.020 inches **Overall Height:** 0.005 inches **Overall Width:** 0.020 inches **Function For Which Designed:** Microwave and switching **Mounting Method:** Press fit **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 100.0 reverse breakdown voltage, dc **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Precious Material And Location:** Eutetic back and top metallization gold **Precious Material:** Gold **Terminal Type And Quantity:** 2 case Shelf Life: N/a **Unit Of Measure:** Demilitarization:

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